SUBSTITUTE FORM PTO-1449 (MODIFIED)							ENT OF COMMERCE	ATTY. DOCKET NO. TAZ-213			SERIAL CE 10/080,496 CF 10/080				
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EXAMINER PATENT NUMBE			R	ISSUE DATE	PATENTEE	CLASS		SUBCLASS		IF APPROPRIATE					
LRUM	A.A	3	9	7	4	0	5	9	08/1976	Murayama					
	А.В	4	4	3	1	9	0	1	02/1984	Hull	• • •				
	A.C	5	1	7	8	7	3	9	01/1993	Barnes et al.					
	A.D	5	2	3	1	3	3	4	07/1993	Paranjpe					
	A.E	5	2	3	4	5	2	9	08/1993	Johnson				\checkmark	
	A.F	5	4	4	9	4	3	3	09/1995	Donohoe				\triangle	
	A.G	5	5	3	4	2	3	1	07/1996	Savas					
	A.H	5	7	6	3	8	5	1	06/1998	Forster et al.			/		
	A.I	5	9	0	0	6	9	9	05/1999	Samukawa et al.					
/	A.J	5	9	0	3	1	0	6	05/1999	Young et al.					
W	A.K	5	9	6	8	3	2	7	10/1999	Kobayashi et al.		/			
					FC	RE	IGN	PAT	ENTS OR PU	BLISHED FOREIGN PA	тент а	PPLICATION	IS		
DOCUMENT NUMBER			PUBLICATION DATE		COUNTRY OR PATENT OFFICE		CLASS	SUBCLASS		TRANSLATION (YES/NO)					
BANN	A.L	W	000	/496	38			24	August 2000	wo					
1	A.M	w))	/115	594			19	March 1998	wo					
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	A.O	w) 99	262	267			27	May 1999	wo					
	A.P	wo) 99/	299	923			17	June 1999	wo					
	A.Q.														
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PLIM	A.R Smithe et al., Calculation of magnetic shielding and ohmic losses from finite thickness Faraday shields used in RF heating of plasmas, J. Appl. Phys. 59 (12) 1986, pp. 3980-3989														
A.S Faulconer, Adverse shielding of the heating field and high ohmic loss introduced by electrostatic shields employed in radio-frequency heating of plasma, J. Appl. Phys. 54 (7) 1983, pp. 3810-3817									employed in radio-						
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EXAMINER Jolephan								DATE CONS	DATE CONSIDERED 6/21 (03/12/23/13						
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SUBSTITUTOFORM R Q-1449 U.S. DEPARTMENT OF COMMERCE ATTY, DOCKET NO. PATENT AND TRADEMARK OFFICE TAZ/213 PIFORMATION DISCLOSURE STATEMENT BY APPLICANT **APPLICANT** MAY 2 1 2002 Jozef Brcka Use several sheets if necessary) FILING DATE February 22, 2002 U.S. PATENT DOCUMENTS EXAMINER ISSUE FILING DATE INITIAL PATENT NUMBER DATE PATENTEE **CLASS** SUBCLASS IF APPROPRIATE B.A 0 6 6 6 0 9 12/1999 DeOrnellas et al. B.B 6 0 5 6 8 4 8 05/2000 Daviet B.C 6 0 8 0 2 7 06/2000 8 Drewery et al. 6 5 6 B.D 6 4 12/2000 Smolanoff et al. 8.E 6 0 4 3 01/2001 DeOrnellas et al. B.F 6 3 6 7 01/2001 DeOmelias et al. B.G 9 0 5 02/2001 Lantsman 8.H 2 6 4 8 2 5 08/2001 Sill 8.1 B.J B.K FOREIGN PATENTS OR PUBLISHED FOREIGN PATENT APPLICATIONS DOCUMENT **PUBLICATION** COUNTRY OR **TRANSLATION** NUMBER DATE PATENT OFFICE **CLASS** SUBCLASS (YES/NO) B.L B.M B.N B.O B.P OTHER DOCUMENTS (Including Author, Title, Date, Place of Publication) 8.R B.S EXAMINER DATE CONSIDERED EXAMINER: Initial if citation considered, whether or not in conformance. Draw line through citation only if not in conformance Include a copy of this form with next communication to applicant.

Substitute Disclosure Form (PTO-1449)



ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18
Stylesheet Version v18.0

Title of Invention

MODIFIED TRANSFER FUNCTION DEPOSITION BAFFLES AND HIGH DENSITY PLASMA IGNITION THEREWITH IN SEMICONDUCTOR PROCESSING

Application Number:

10/080496

Confirmation Number:

8492

First Named Applicant:

Jozef Brcka

Attorney Docket Number: TAZ213

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Art Unit:

1763

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Examiner:

Luz L.

GROUP 1700

Search string: (6287435).pn.

<u>Certification:</u> This Information Disclosure Statement was submitted under the following conditions, which satisfies the requirement under 37 CFR 1.97(e). The filer certified:

That each item of information contained in the information disclosure statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the information disclosure statement.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
1	6287435	2001-09-11	Drewery et al.		· 	<u> </u>

Signature

Examiner Name	Date
Dejado	12/23/05